

PHOTOVOLTAIC SERIES

PLANAR DIFFUSED SILICON PHOTODIODES



APPLICATIONS

- Colorimeters
- Photometers
- Spectroscopy Equipment
- Fluorescence

FEATURES

- Ultra Low Noise
- High Shunt Resistance
- Wide Dynamic Range
- Blue Enhanced

The Photovoltaic Detector series is utilized for applications requiring high sensitivity and moderate response speeds, with an additional sensitivity in the visible-blue region for the blue enhanced series. The spectral response ranges from 350 to 1100 nm, making the regular photovoltaic devices ideal for visible and near IR applications. For additional sensitivity in the 350 nm to 550 nm region, the blue enhanced devices are more suitable.

These detectors have high shunt resistance and low noise, and exhibit long term stability. Unbiased operation of these detectors offers stability under wide temperature variations in DC or low speed applications. For high light levels (greater than 10mW/cm²), the Photoconductive Series detectors should

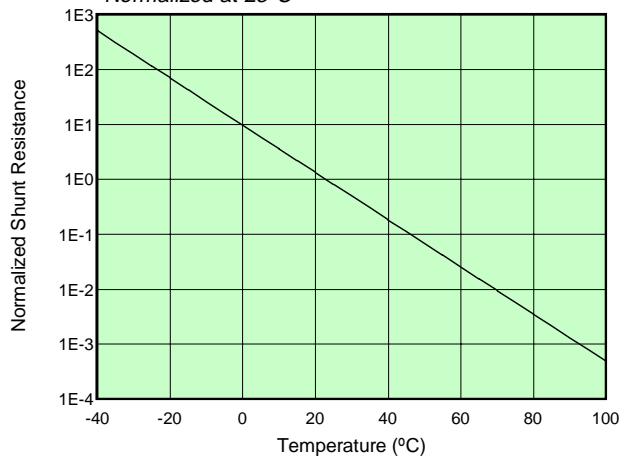
be considered for better linearity.

These detectors are not designed to be reverse biased! Very slight improvement in response time may be obtained with a slight bias. Applying a reverse bias of more than a few volts (>3V) will permanently damage the detectors. If faster response times are required, the Photoconductive Series should be considered.

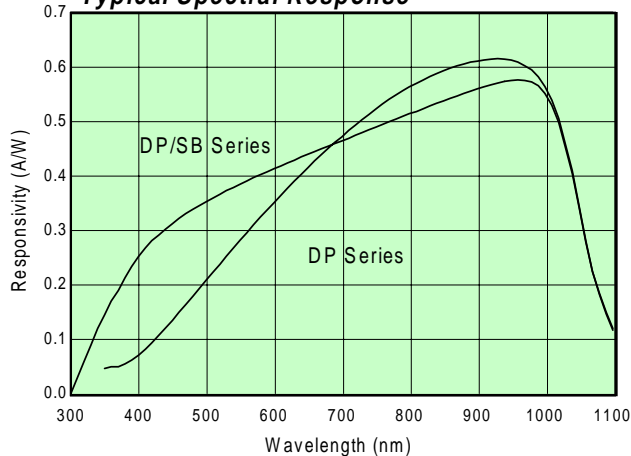
Refer to the *Photovoltaic Mode (PV)* paragraph in the "Photodiode Characteristics" section of this catalog for detailed information on electronics set up.

Typical Shunt Resistance vs Temp

Normalized at 23°C



Typical Spectral Response



Model No.	Active Area		Responsivity (A/W)						Capacitance (pF)	Shunt Resistance (M-ohm)		NEP (W/√Hz)	Rise Time (ns)	Temp Range (°C)		Package Style ¶						
	Area (mm ²)	Dimension (mm)	400 nm		632 nm		970 nm		0 V	-10 mV		0V 970 nm	0 V 632 nm 50 ohm	Operating	Storage							
			min	typ	min	typ	min	typ	typ	min	typ	typ	typ									
DP SERIES, METAL PACKAGE																						
PIN-2DPI *	1.1	.81 x 1.37							150	1000	10000	2.1 e -15	30	-40 ~ +100 -55 ~ +125		4 / TO-18						
PIN-125DPL	1.6	1.27 sq.							160						8 / TO-18							
PIN-3CDPI	3.2	1.27 x 2.54							320	750	5000	3.0 e -15	50			4 / TO-18						
PIN-3CDP																7 / TO-18						
PIN-5DPI	5.1	2.54							500	500	4000	3.4e -15	60			2 / TO-5						
PIN-5DP																5 / TO-5						
PIN-13DPI	13	3.6 sq							1200	350	3500	3.6 e -15	150			2 / TO-5						
PIN-13DP																5 / TO-5						
PIN-6DPI	16.4	4.57	.07	.12	.33	.40	.55	.60	2000	200	3000	3.9e -15	220			3 / TO-8						
PIN-6DP																				6 / TO-8		
PIN-44DPI	44	6.6 sq														4300	100	2000	4.8 e -15	475		3 / TO-8
PIN-44DP																						6 / TO-8
PIN-10DPI	100	11.28													9800	50	1000	6.8e -15	1000		10 / Lo-Prof	
PIN-10DP																					11 / BNC	
PIN-25DP	613	27.9													60000	2	50	3.0 e -14	6600		12 / BNC	
DP SERIES, PLASTIC PACKAGE §																						
FIL-3V	3.2	1.27 x 2.54													320	750	5000	3.0 e -15	20	-10 ~ +60 -20 ~ +70		14 / Plastic
FIL-5V	5.1	2.54													500	500	4000	3.4e -15	60			
FIL-20V	16.4	4.57							.08	.12	.33	.40	.55	.60	2000	200	3000	3.9e -15	220			
FIL-44V	44	6.6 sq													4300	100	2000	4.8 e -15	475			15 / Plastic
FIL-100V	100	11.28	9800	50	1000	6.8e -15	1000															
PIN-220DP	200	10 x 20	20000	15	300	1.2 e -14	2200								26 / Plastic							
SUPER BLUE ENHANCED DP/SB SERIES (All Specifications @ = 410nm, V_{BIAS} = 0V, R_L = 50)																						
Model No.	Active Area/Dimension		Responsivity (A/W)		Capacitance (pF)	Rsh (M-ohm)	NEP (W/√Hz)	Operat. Current (mA)	Rise Time (ns)	**	**	Package Style ¶										
	mm ²	mm	Min	Typ	Typ	Min	Typ	Max	Typ													
PIN-5DP/SB	5.1	2.54	0.15	0.20	450	150	5.2 e -14	2.0	0.2	-10 ~ +60 -20 ~ +70		5 / TO-5										
PNI-10DP/SB	100	11.28			8800	10	2.0e -13	10.0	2.0			11 / BNC										
PIN-10DPI/SB													10 / LoProf									
PIN-220DP/SB	200	10 x 20			17000	5	2.9 e -13	10.0	4.0			26 / Plastic										

* The 1 suffix on the model number is indicative of the photodiode chip being isolated from the package by an additional pin connected to the case.

§ The photodiode chips in FIL series are isolated in a low profile plastic package. They have a large field of view as well as in line pins.

** Operating Temperature: -40 to +100 °C, Storage Temperature: -55 to +125 °C

For MECHANICAL DRAWINGS Click Here